



# **Fabrication and Characterizations for Efficient CdTe-based Solar Cells at University of Toledo**

**Deng-Bing Li**

**10/19/2022**

# Wright Center for Photovoltaics Innovation and Commercialization (PVIC)

## Collins Group

**Optical Spectroscopies:**  
Ellipsometry

**Solar Cell Fabrications:**  
CIGS, CIS

## Ellingson Group

**Optical Spectroscopies:**  
PL, TRPL, TA

**Device fabrication**  
Bifacial Solar cell  
back contact material

## Heben Group

**Production and Grid  
Integration**  
**Instrument Development**  
**Device Fabrication and  
Characterization**

## Podraza Group

**Optical Spectroscopies:**  
Ellipsometry

## Yan Group

**Solar Cell Fabrications**  
CdTe, Perovskite

**DFT Calculations**

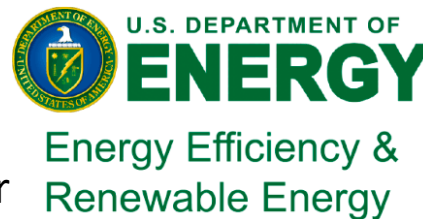
**Electrical  
Characterizations**

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## Off-Campus Collaborators

Prof. Feng Yan in University of Alabama  
Dr. Chuanxiao Xiao and Chunsheng Jiang  
from NREL  
Dr. Jonathan D. Poplawsky and David A. Culler  
from ORNL

## Funding Support



## Substrate Supply



**PILKINGTON**  
NSG Group Flat Glass Business

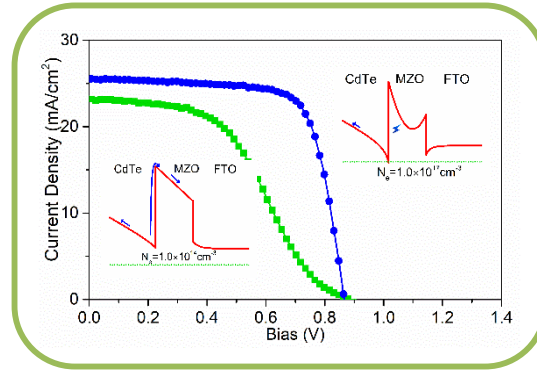
**University of Toledo**



# Roadmap for High Efficiency Solar Cells in UT

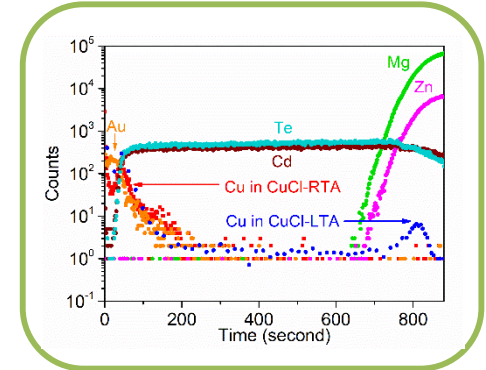


**Back Surface Etching-15%**  
Sol. RRL 3(2019), 1800304



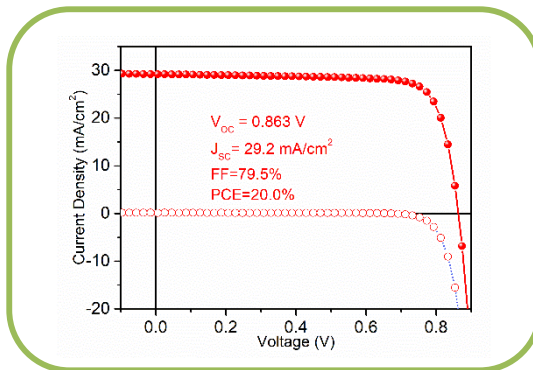
**ZMO Conductivity-16.1%**

ACS Appl. Energy Mater. 2(2019), 2896–2903  
Prog. Photovolt. Res. Appl. 27(2019), 1115–1123

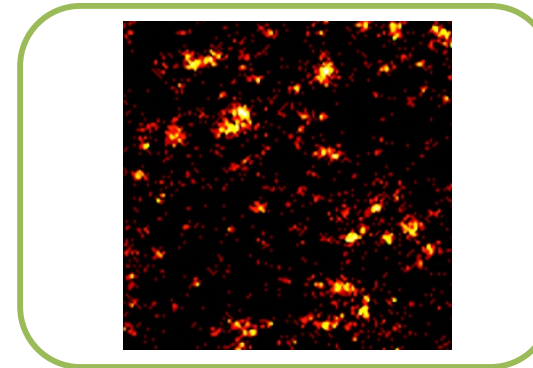


**Cu Engineering-17.5%**

Nano Energy 73 (2020)  
ACS Appl. Mater. Interfaces 2021, 13,  
38432–38440



**Se incorporation-20%**  
unpublished



**Ex-situ GrV Doping-18%, collaborate with Prof.  
Feng Yan in UA**

Nature Energy volume 6(2021), 715–722

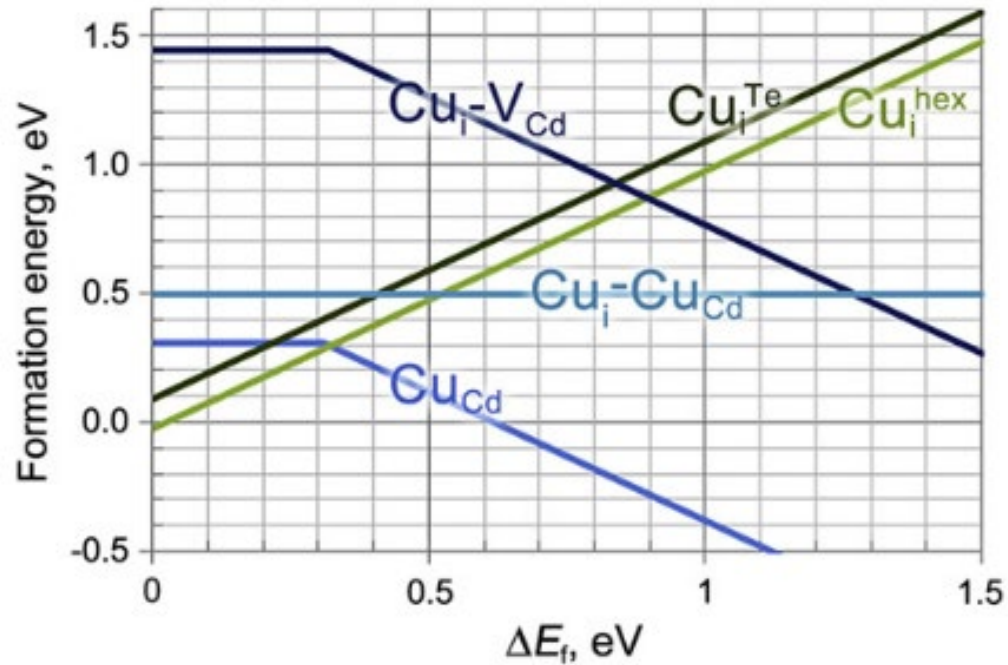




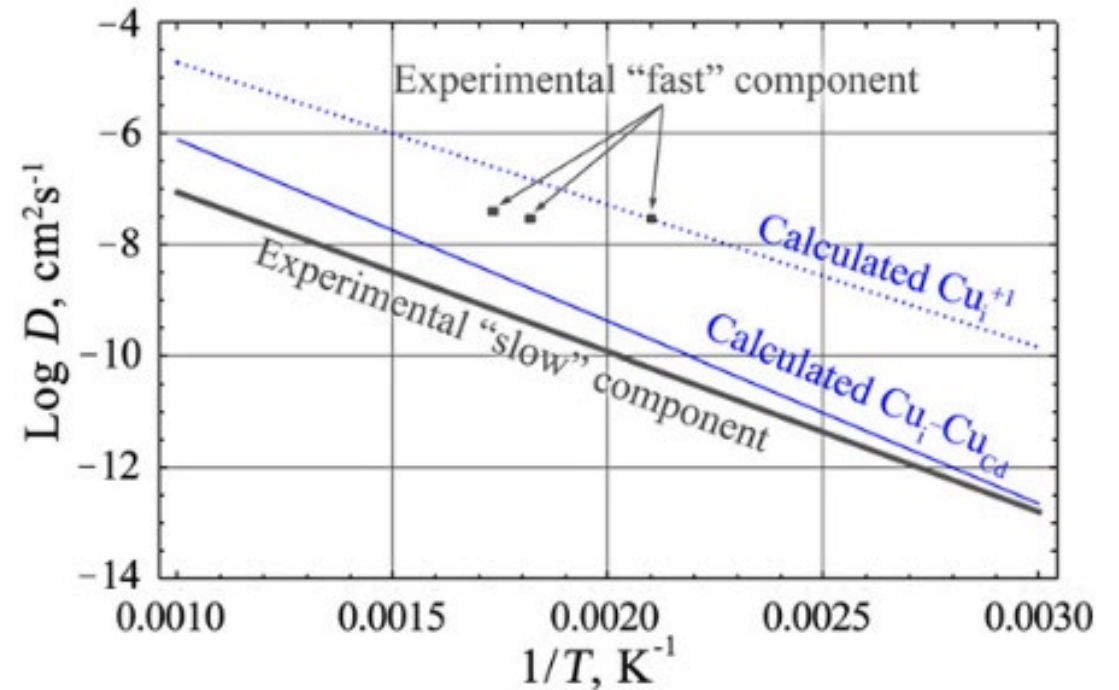
# Contents

- **Cu Engineering**
- **Se Incorporation**
- **IGO Emitter Exploration**
- **Ultra Thin CdSeTe Solar Cells**
- **Bifacial CdTe Solar Cells**
- **New Capability in UT**

## Compensatory Defect



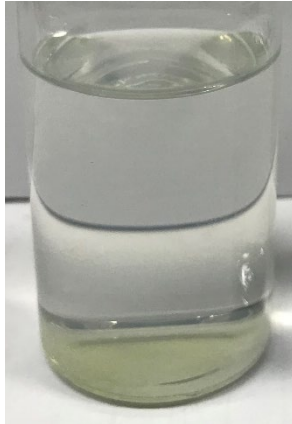
## High Diffusion Coefficient



**Minimize Cu concentration** and **optimal distribution** are required to maximize the hole density and device performance in CdTe

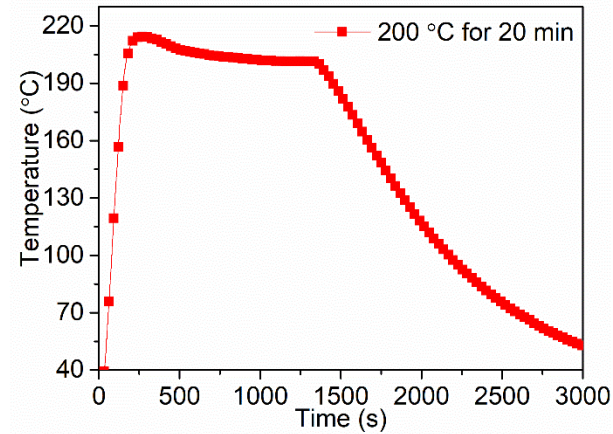
# Cu Engineering

CuCl in ET(3.10 $\mu$ g/ml)

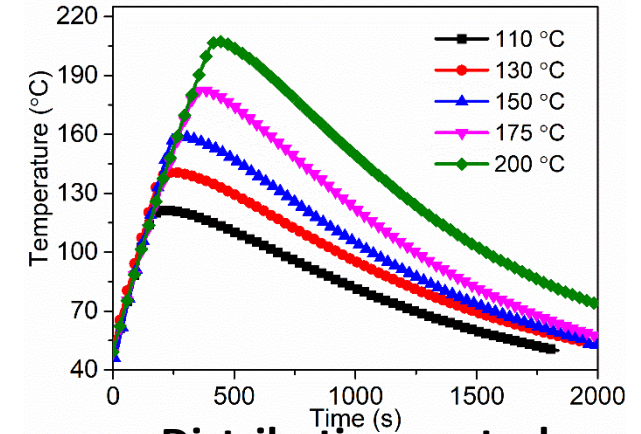


Dosage control

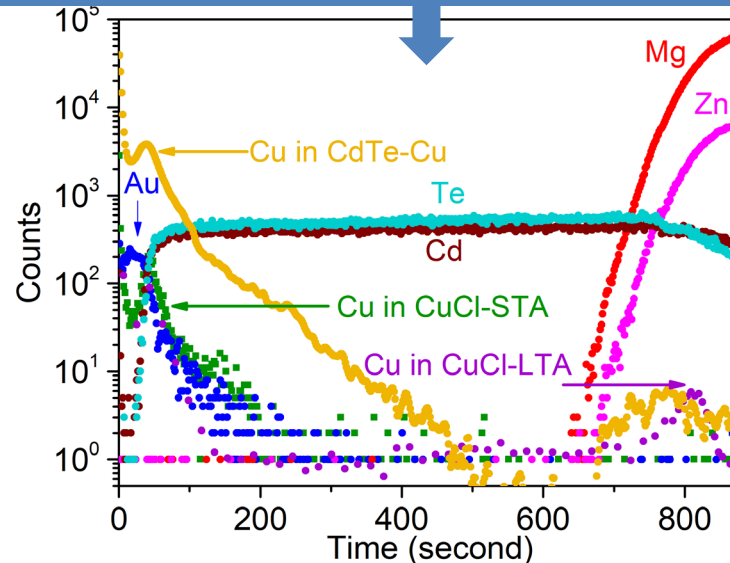
Traditional Cu activation process



Short Thermal Annealing



Distribution control

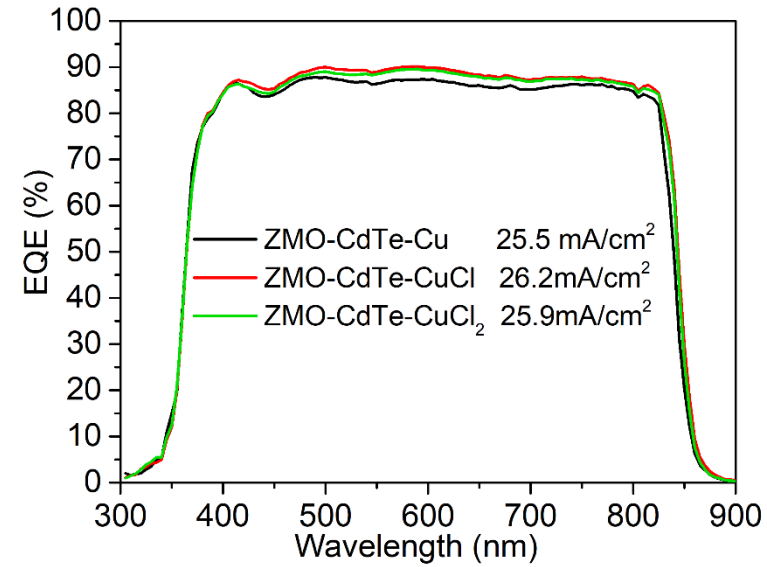
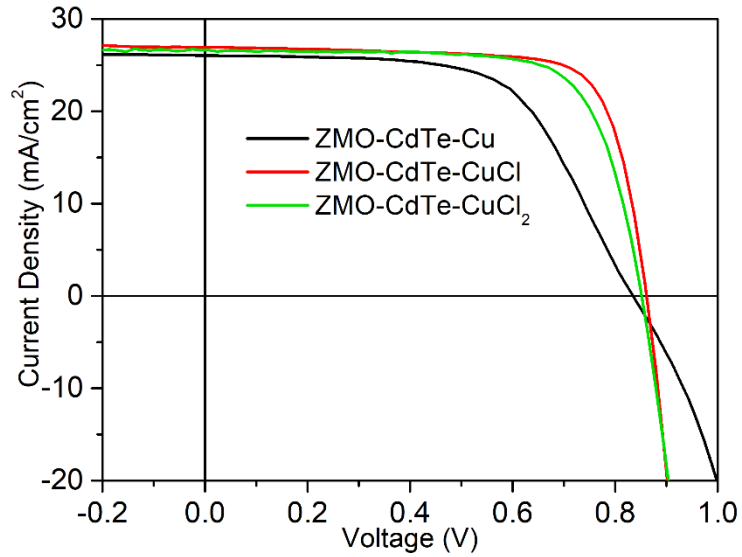


Less Cu dosage:  
0.019nm vs. 3-4nm

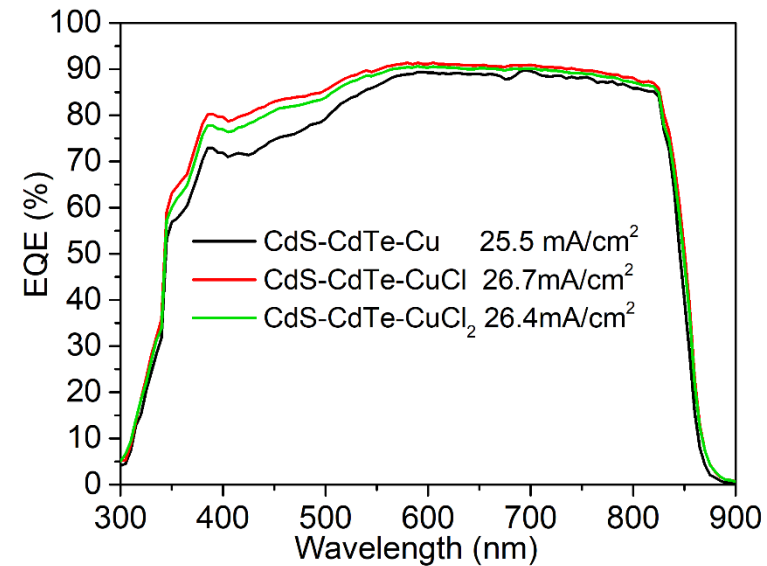
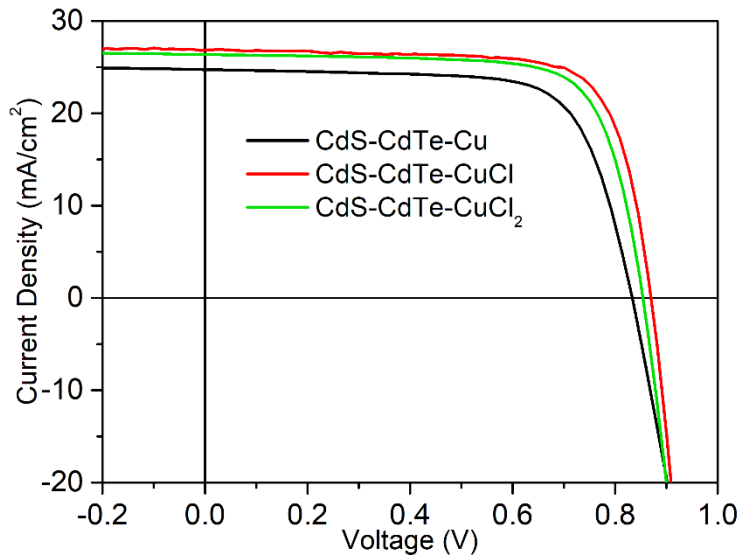
Desired Cu distribution:  
less at the front region



# Cu Engineering

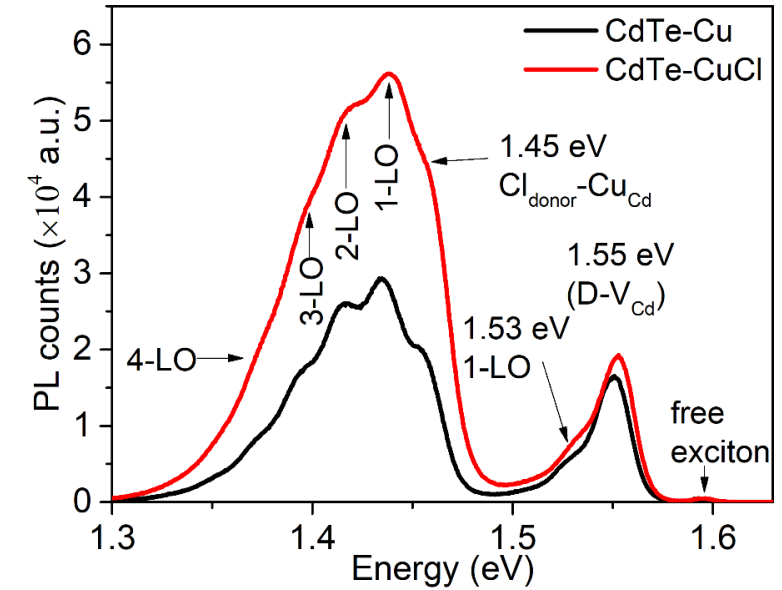
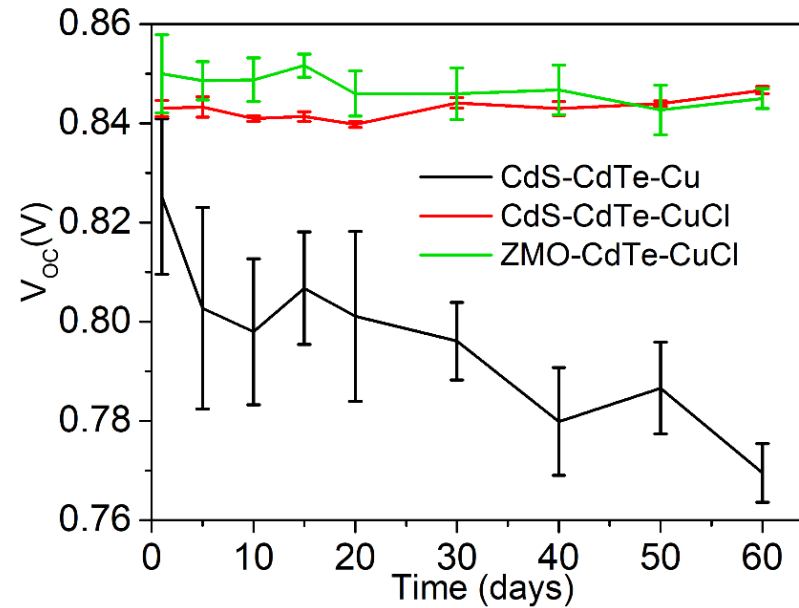
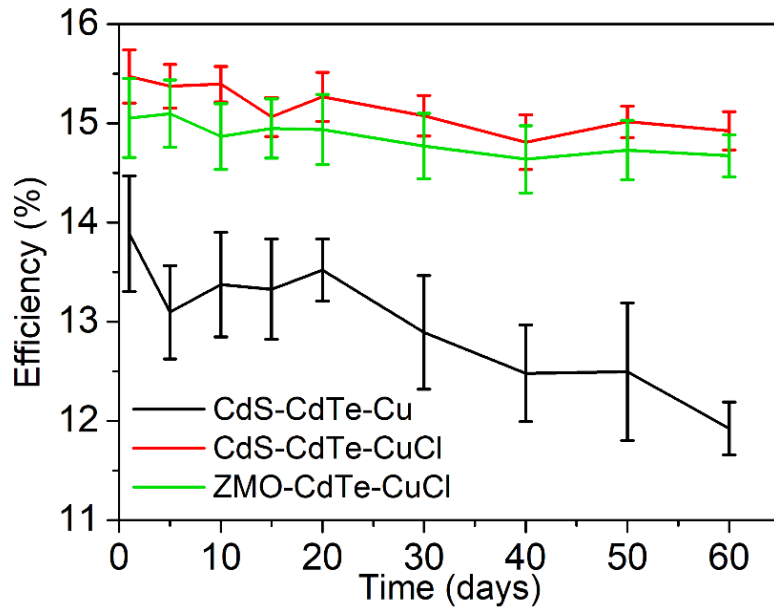


With ZMO as buffer layer  
17.5% with MgF<sub>2</sub>



With CdS as buffer layer  
17.2% with MgF<sub>2</sub>

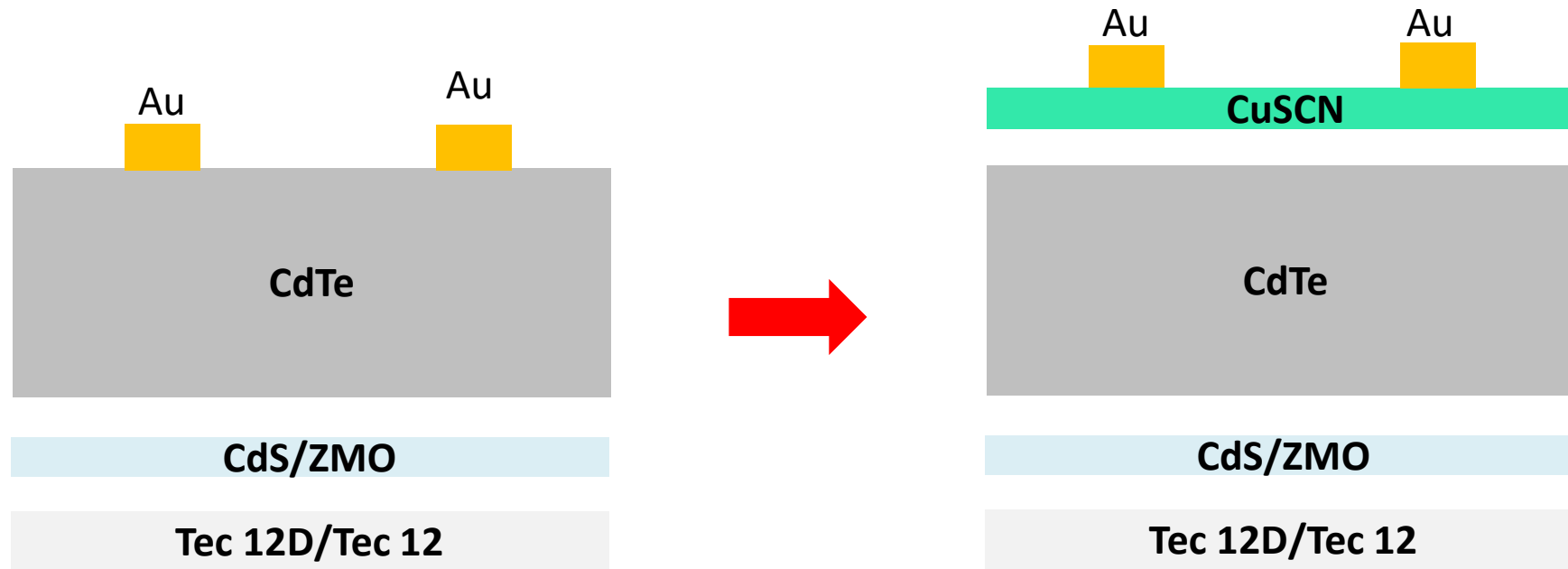
## Improved Stability



- More substitutional  $Cu_{Cd}$  can be observed from low temperature PL spectra and less expected  $Cu_i$  and other compensatory defects can be expected.
- Higher device stability than traditional can be achieved with this Cu engineering strategy



# Cu Engineering



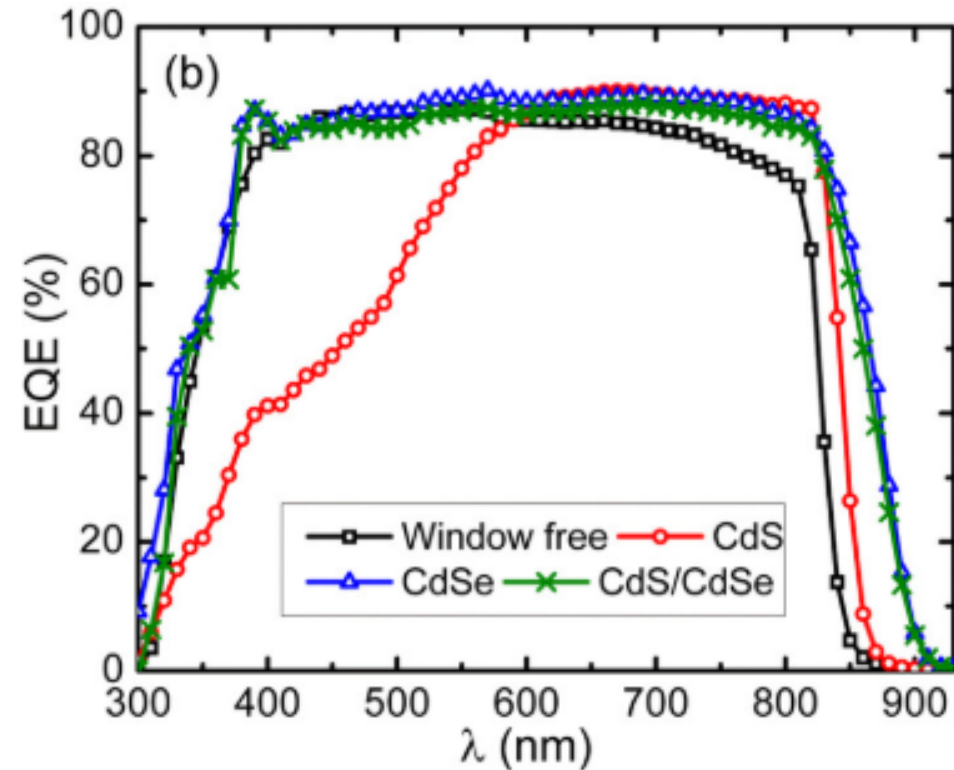
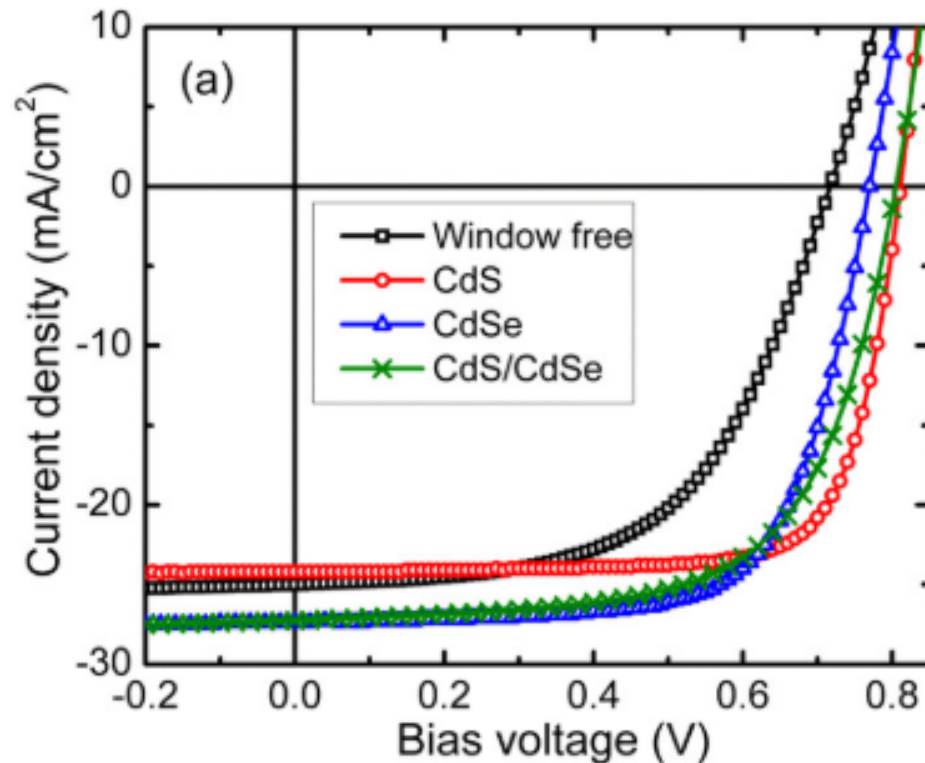
**CuCl as dopant**

**CuSCN as dopant + Hole transport layer**

## Enhancing the photo-currents of CdTe thin-film solar cells in both short and long wavelength regions

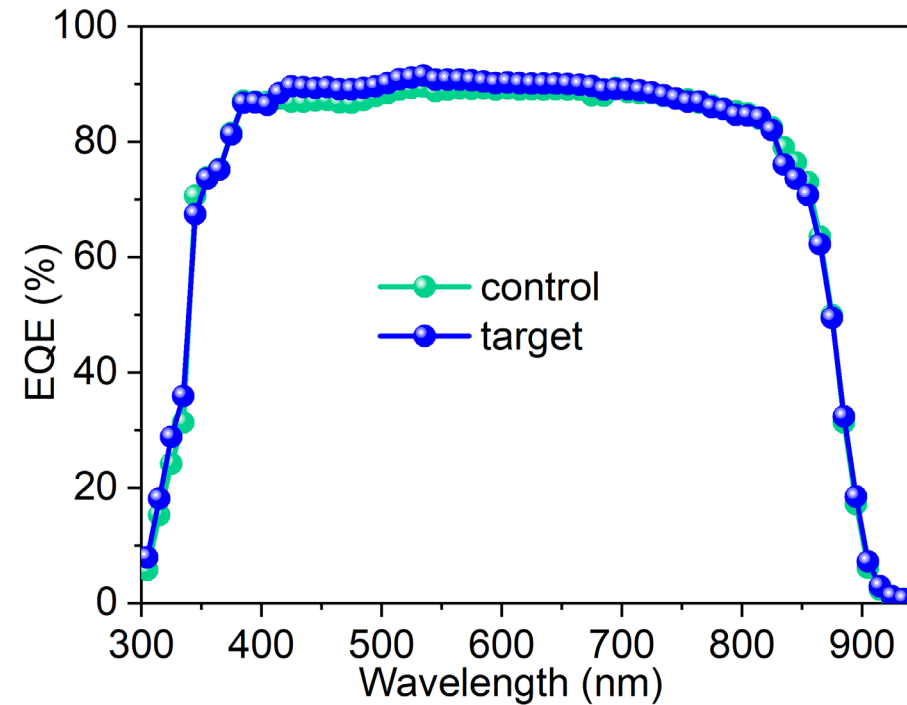
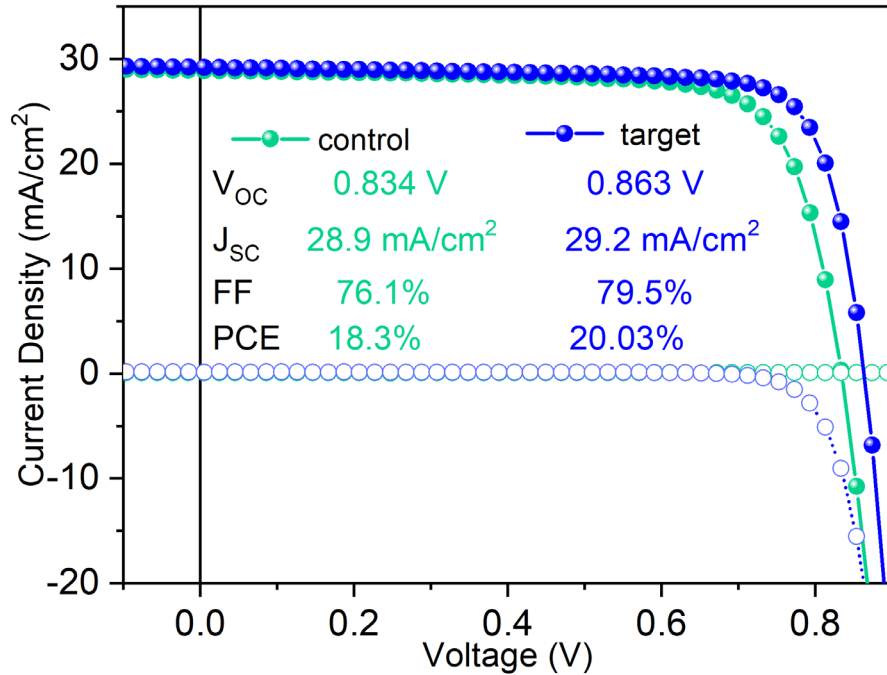
Naba R. Paudel<sup>a)</sup> and Yanfa Yan<sup>b)</sup>

*Department of Physics and Astronomy, and Wright Center for Photovoltaics Innovation and Commercialization, The University of Toledo, Toledo, Ohio 43606, USA*



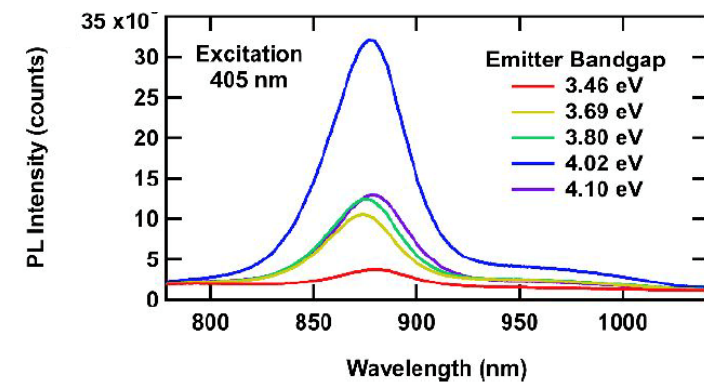
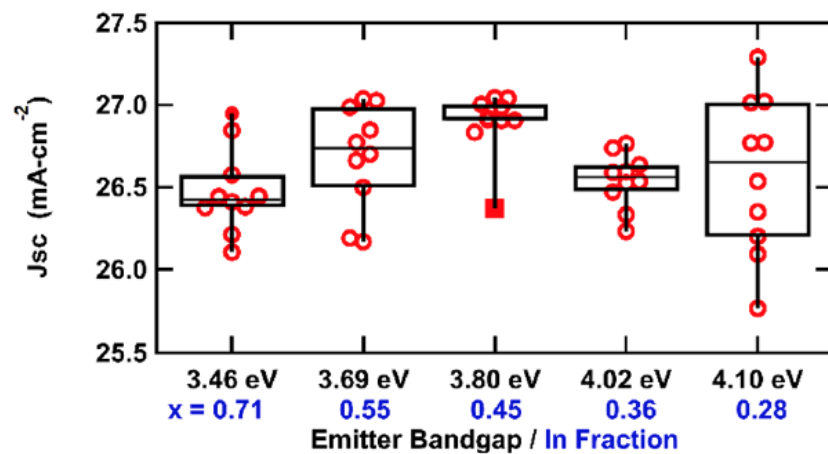
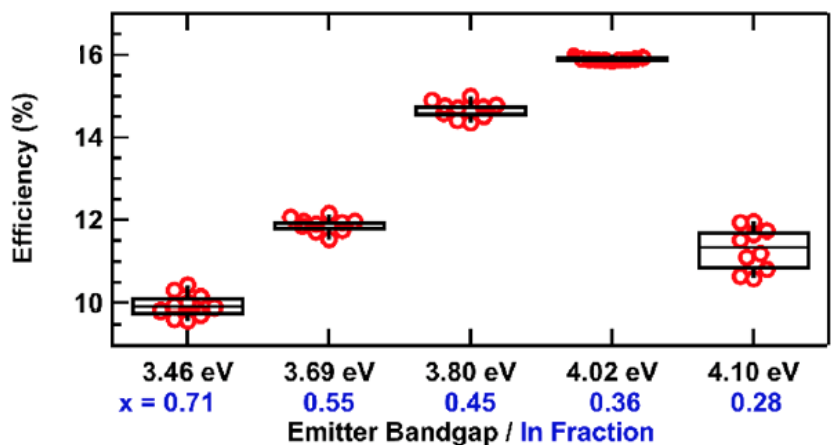
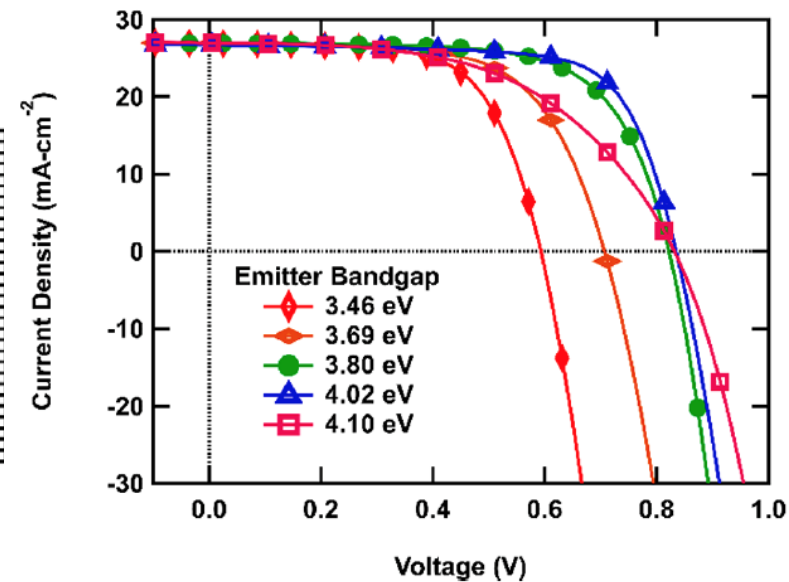
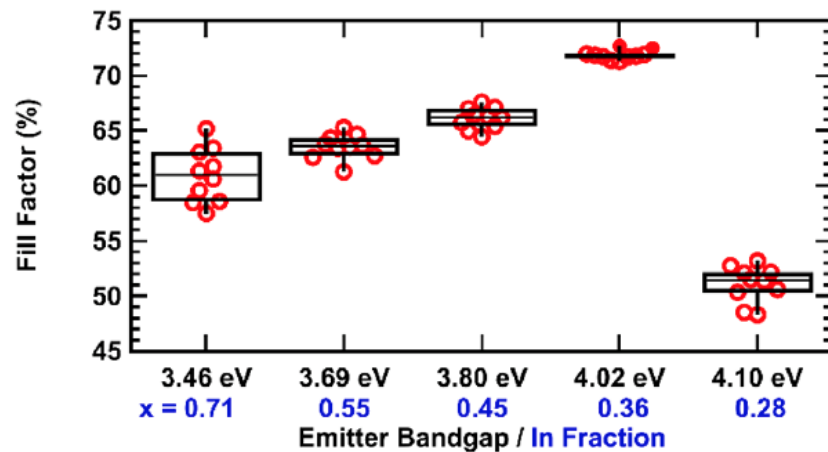
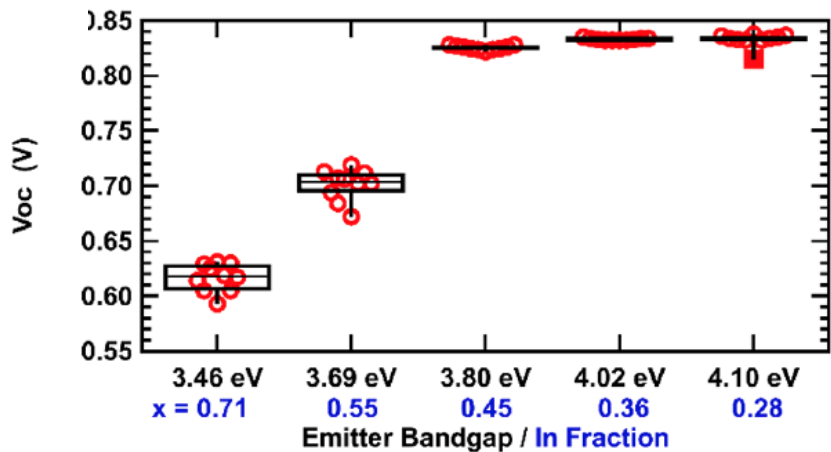


# Se Incorporation



**20% PCE was successfully demonstrated with the Cd(Se,Te) region with composition and bandgap gradient.**

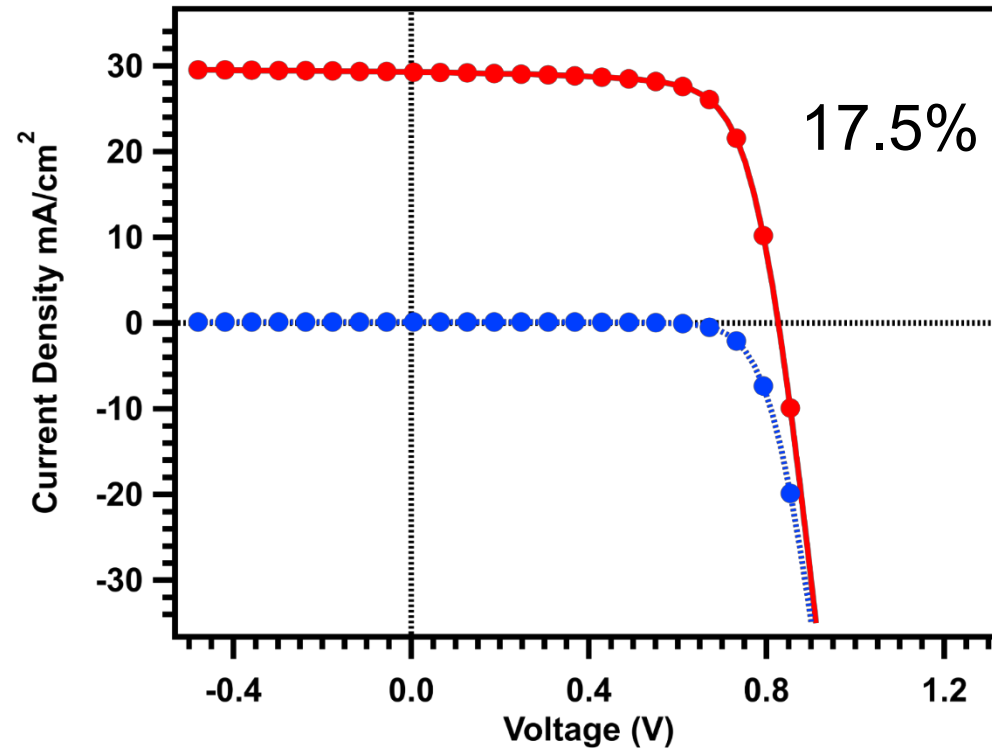
# TEC 10/IGO/CdSe/CdTe/CuCl<sub>2</sub>/Au





# TEC 12/IGO/CdSe/CdTe/CuCl<sub>2</sub>/Au

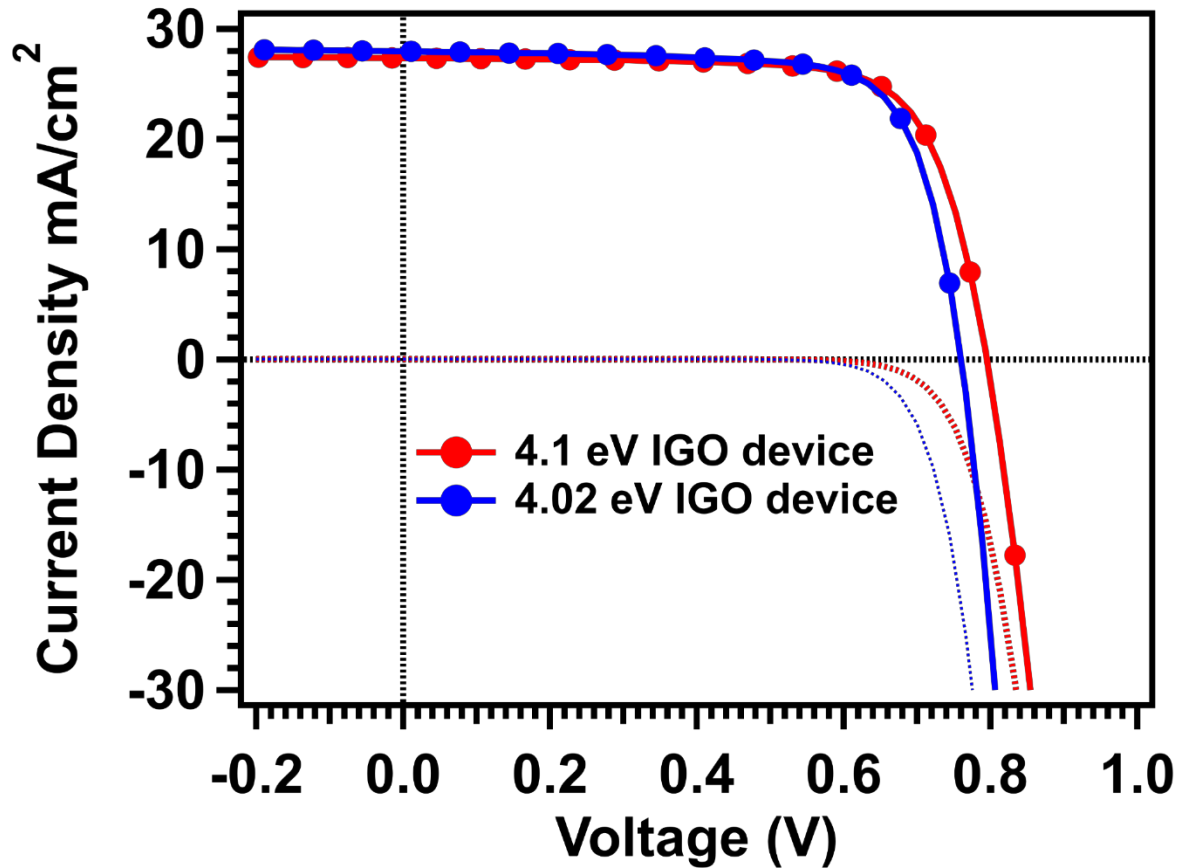
Voc: 827 mV  
Jsc 29.2 mA/cm<sup>2</sup>  
FF: 72.3%  
PCE = 17.5%



In comparison to MZO, fabrication is less sensitive to P<sub>O<sub>2</sub></sub>



# Willow<sup>®</sup> Glass (100 μm)/ Cd<sub>2</sub>SnO<sub>4</sub>/IGO/CdSe (90 nm) /CdTe



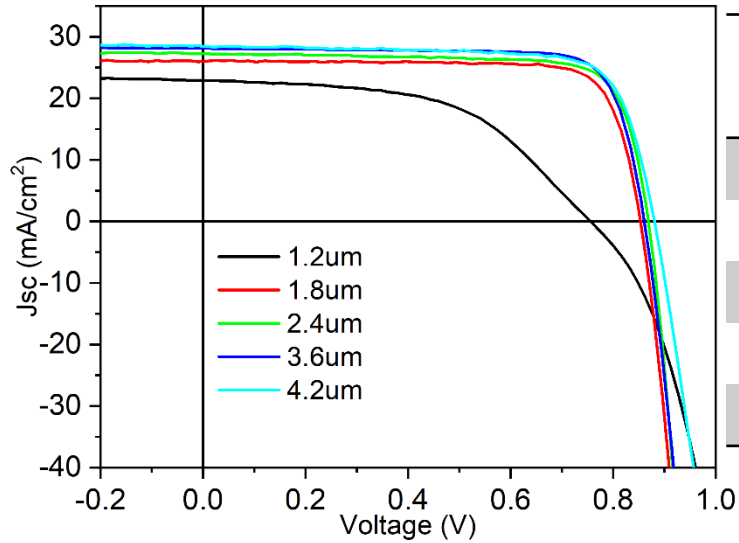
- Larger bandgap of IGO (4.1 eV) is needed for Cd<sub>2</sub>SnO<sub>4</sub>/IGO/CdSeTe
- May be due to chemistry at Cd<sub>2</sub>SnO<sub>4</sub>/IGO interface
- 16.1% on Willow is very close to the record\*

\* 16.4% by Mahabaduge et al, Appl. Phys. Lett. 106, 133501 (2015)

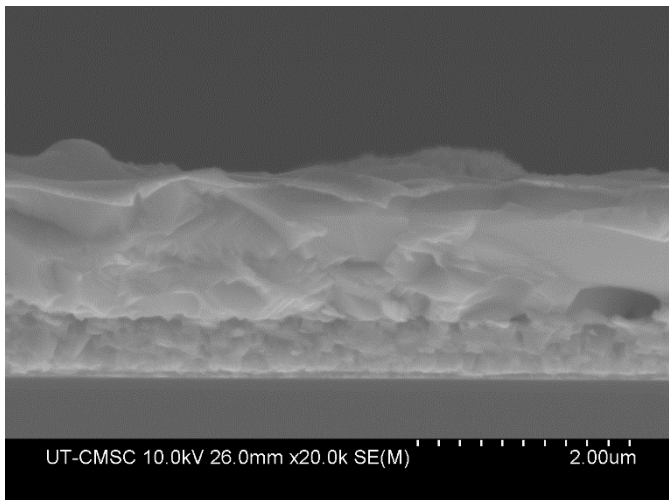
Average/Max PV parameters

Sample	Voc (mV)	Jsc (mAcm <sup>2</sup> )	FF (%)	PCE (%)
4.02 eV IGO	756/760	27.8/27.9	73.7/74.6	15.5/15.85
4.1 eV IGO	790/795	26.8/27.3	73.5/74.1	15.6/16.13

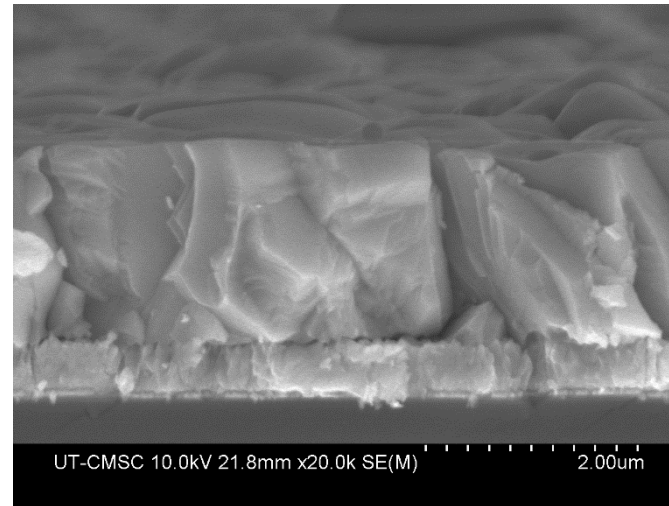
# Ultra-thin CdSeTe Solar Cells



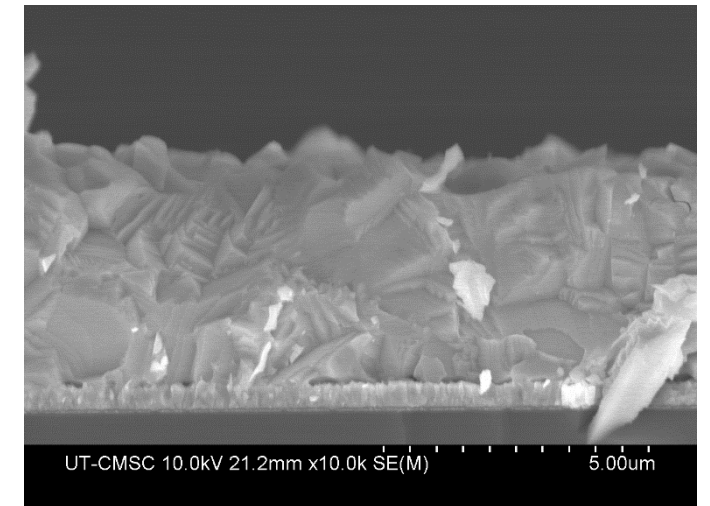
samples	$V_{OC}$ (V)	$J_{SC}$ (mA/cm <sup>2</sup> )	FF (%)	PCE (%)	$R_s$ ( $\Omega \cdot \text{cm}^2$ )	$R_{SH}$ ( $\Omega \cdot \text{cm}^2$ )
<b>1.2um</b>	0.756	22.9	53.0	9.18	11.8	556
<b>1.8um</b>	0.853	26.0	<b>80.6</b>	17.9	3.1	2215
<b>2.4um</b>	0.868	27.3	79.9	18.9	2.8	1194
<b>3.6um</b>	0.861	28.2	79.9	19.4	1.3	1760
<b>4.2um</b>	<b>0.881</b>	28.4	76.7	19.2	2.1	1241



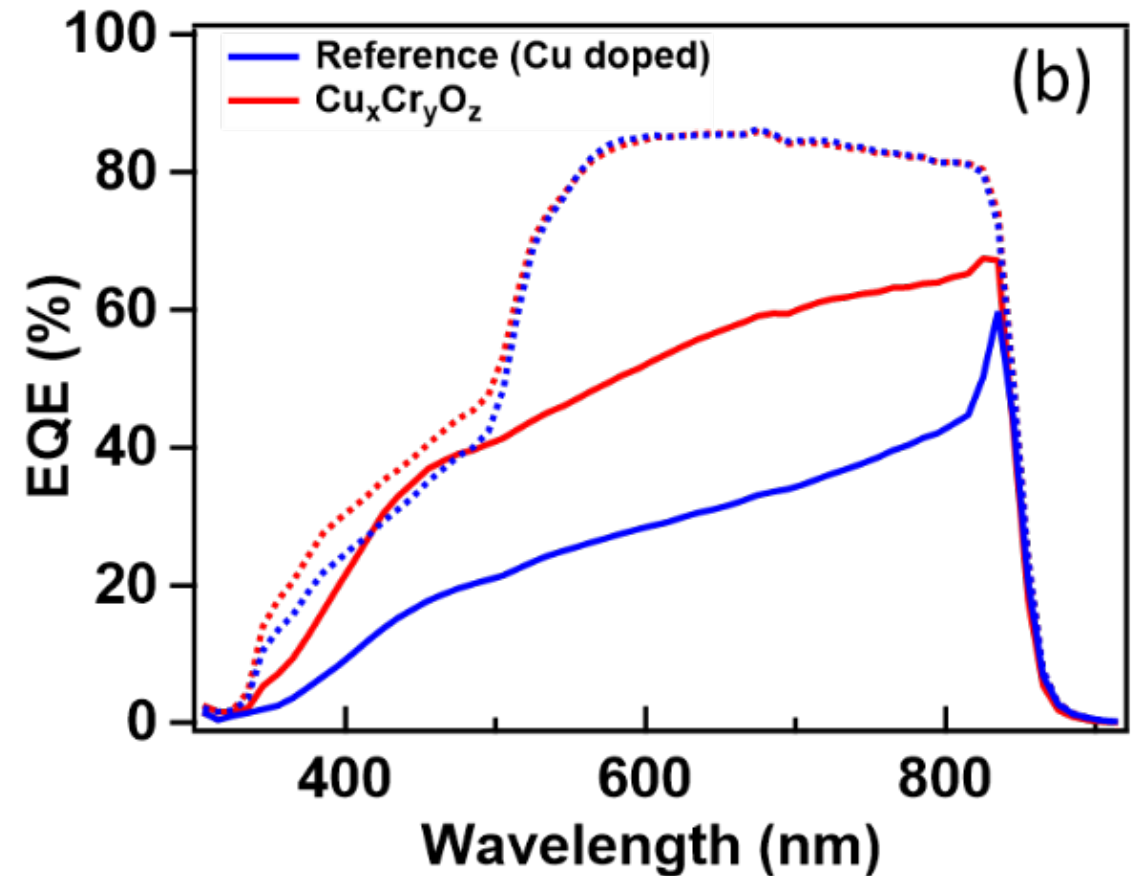
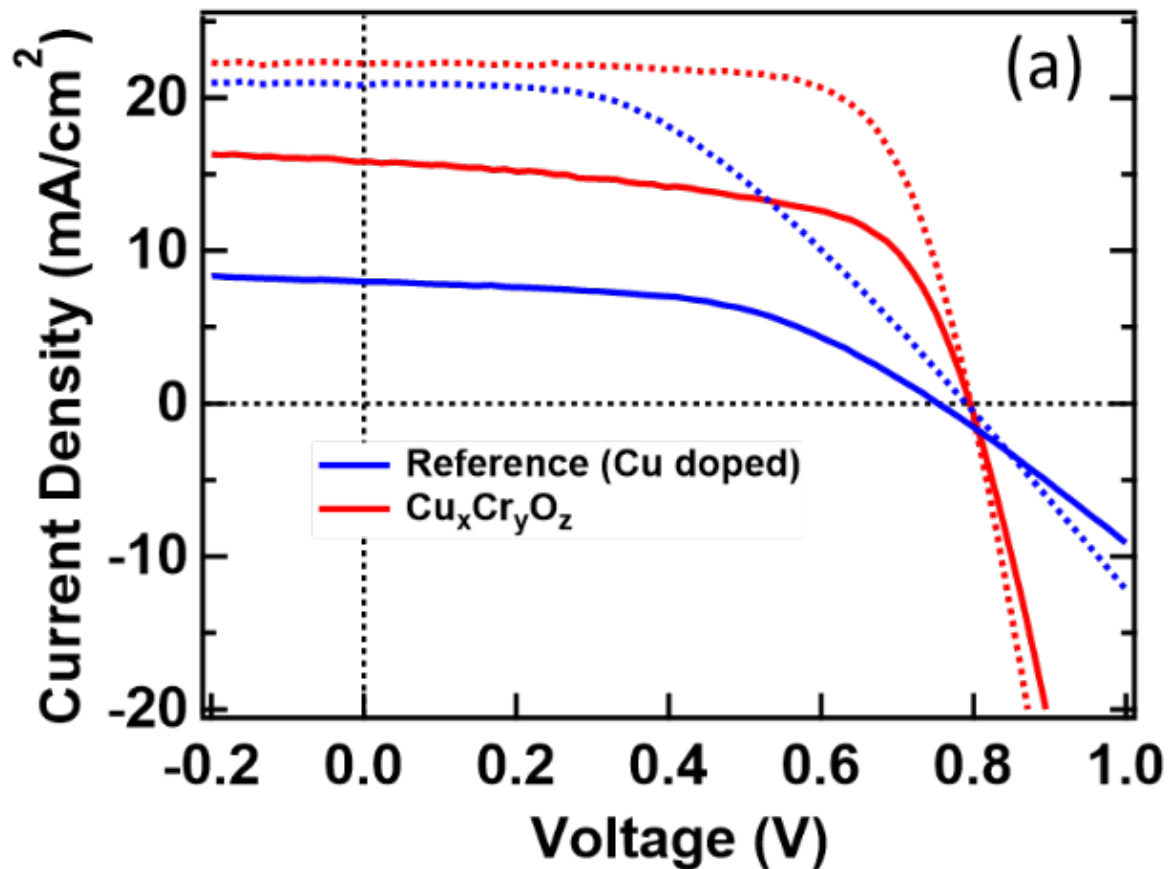
1.2 $\mu\text{m}$



1.8 $\mu\text{m}$



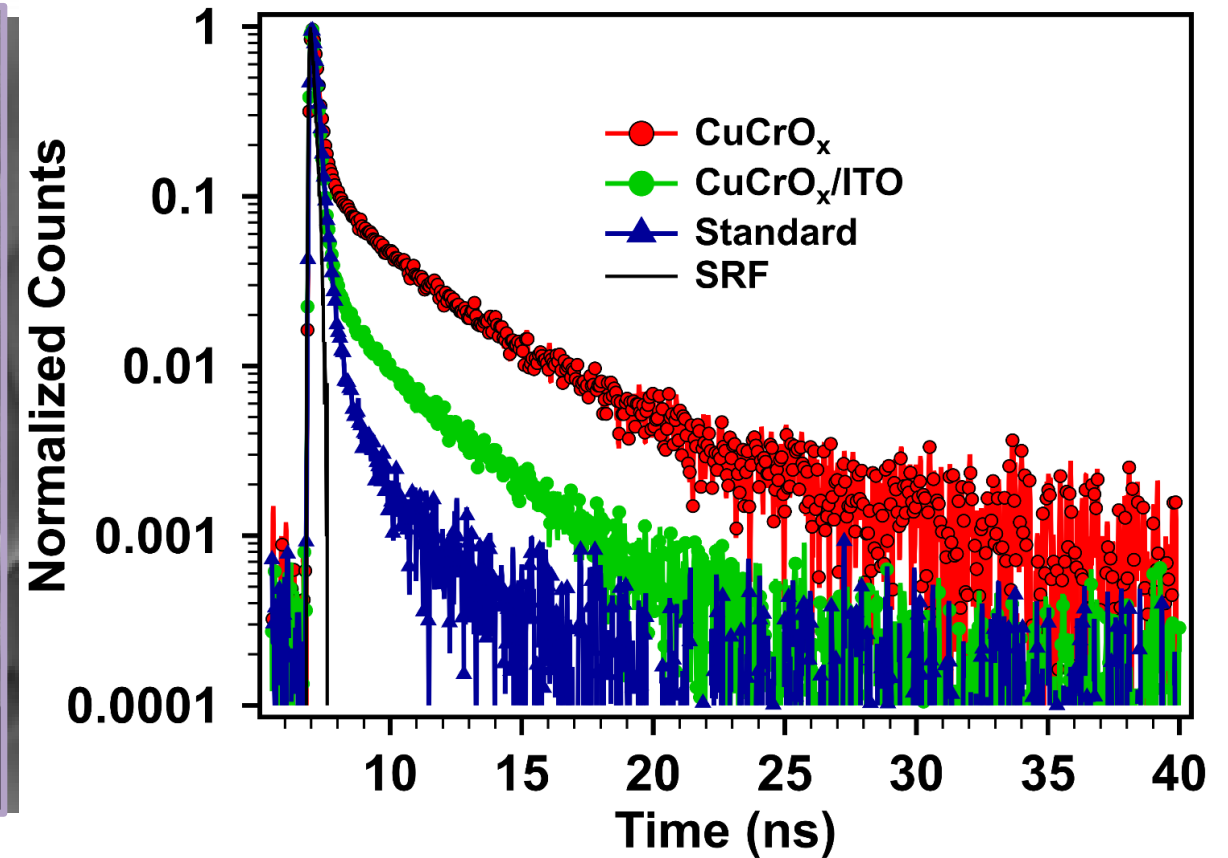
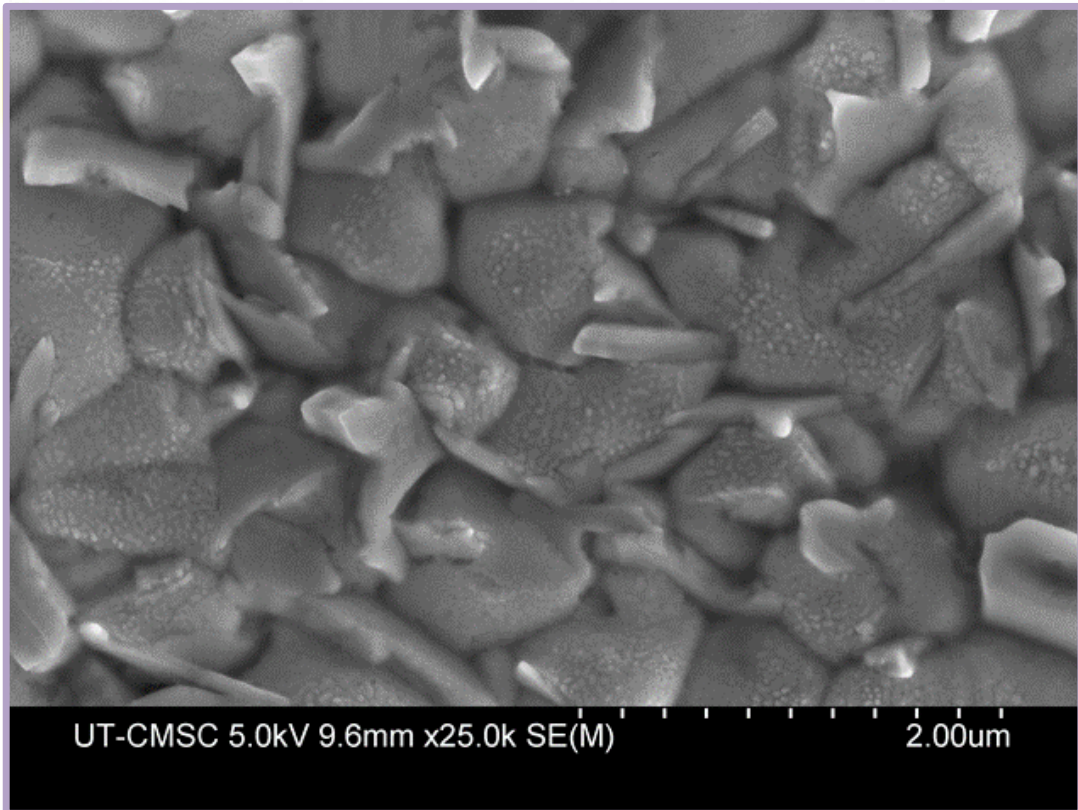
3.6 $\mu\text{m}$



Performance data of bifacial CdTe/CdS solar cells (solid and dotted lines correspond to back and front illumination, respectively). Reference corresponds to a Cu-doped device with ITO contact, and Cu<sub>x</sub>Cr<sub>y</sub>O<sub>z</sub> refers to the device with buffer and ITO back contact. (a) J-V characteristics, and (b) EQE.



# Bifacial – notes and next steps

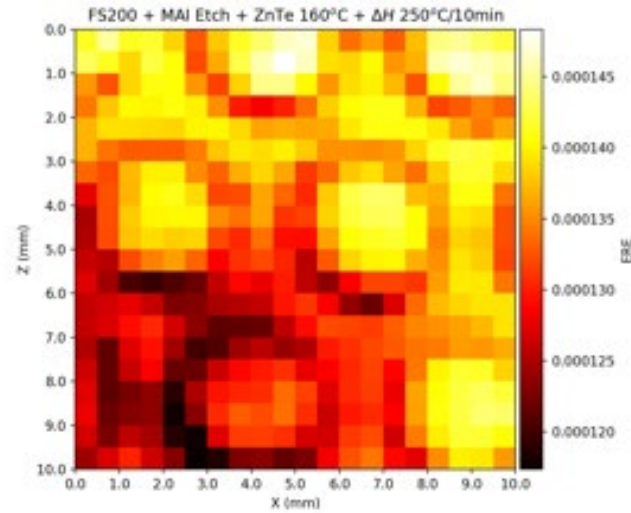


- Identify composition and structure of (CdClO<sub>x</sub>?) platelets, which correlate with improved back-illuminated performance → material of interest as passivant. Removing platelets w/ HCl etch kills back-side performance.
- Challenges associated with CdSeTe film stack, and achieving simultaneous high PCE and good bifaciality.
- Move to As-doped CST brings new challenges and opportunities (stay tuned).

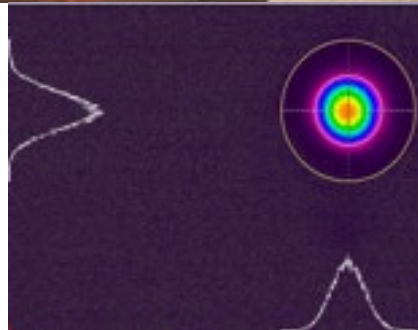
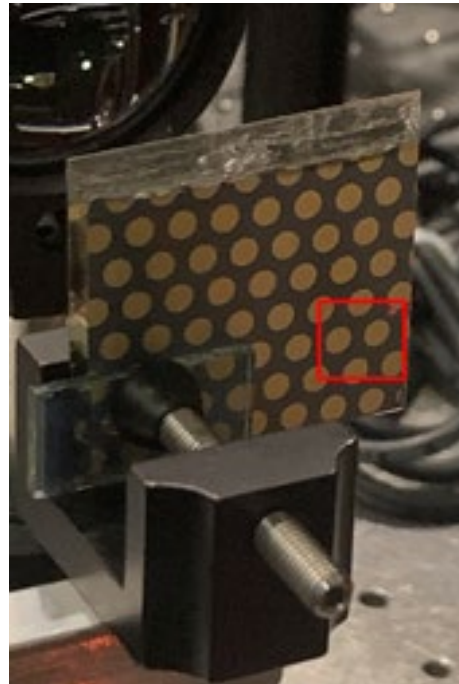
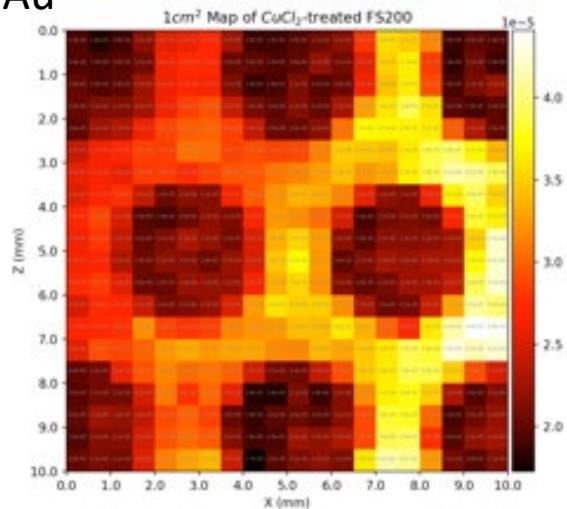
# New capability: ERE mapping

(thanks to ASU for early help: Ohno/Holman/Zhang)

$\text{CH}_3\text{NH}_3\text{I}$  "etch" + Cu:ZnTe

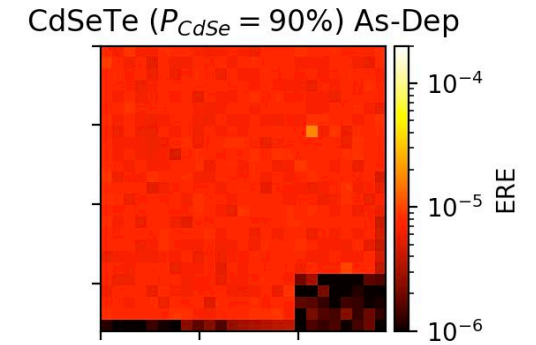


Cu:Au

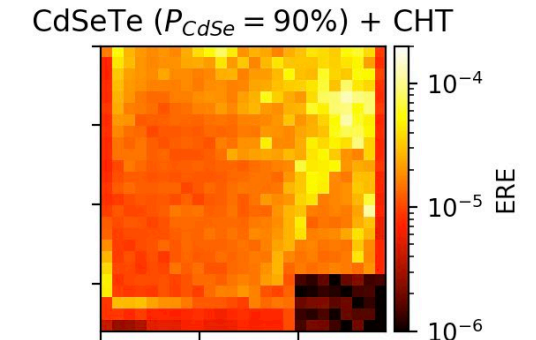


# Combinatorial investigations (off-axis co-evap of CdTe /CdSe)

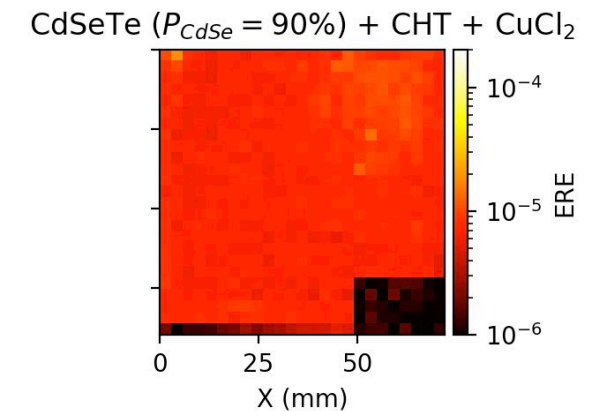
As-Deposited



After CdCl<sub>2</sub>



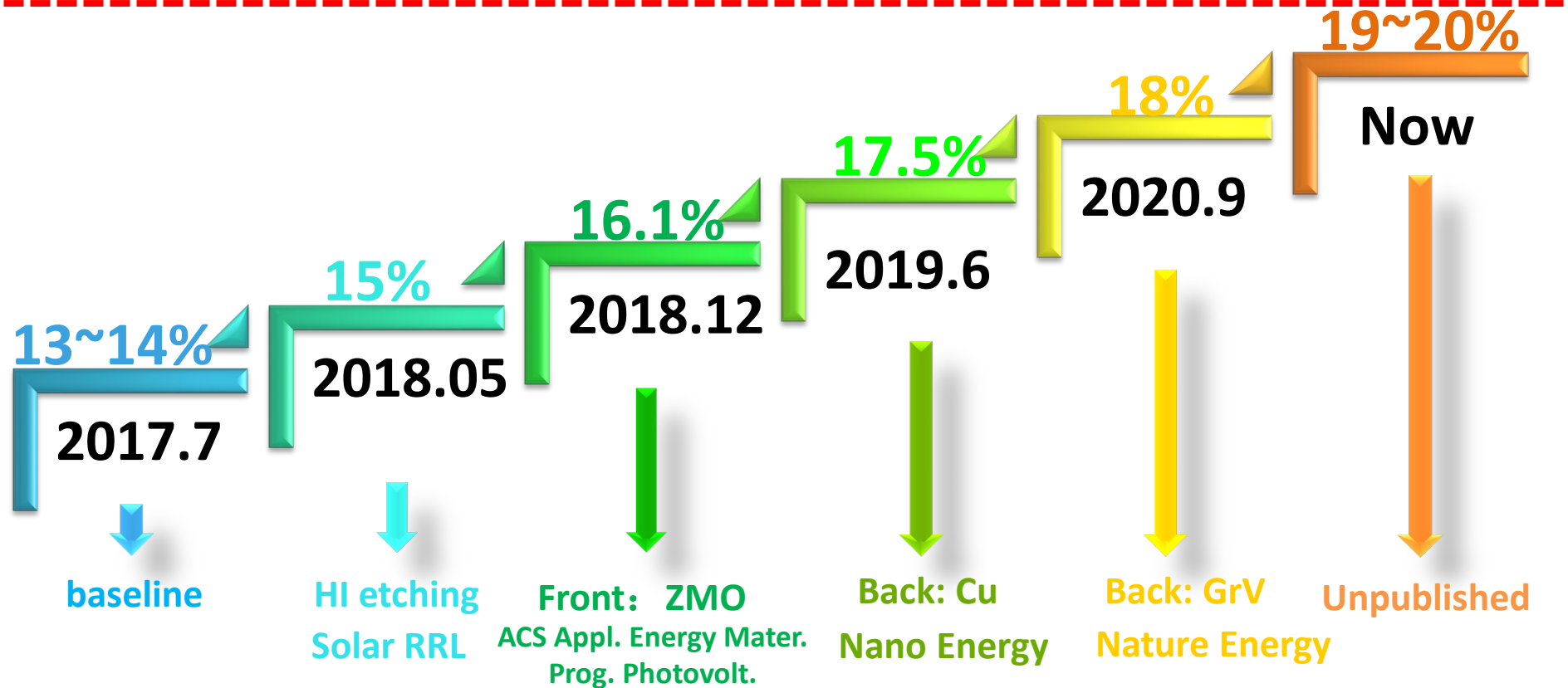
After CuCl<sub>2</sub>





# Summary

First Solar: 22.1%



**UT can further improve its contribution to CdTe community and advance the CdTe photovoltaic technology!**



# Thank You for Your Attention!

## Questions?

There are other advances going on at UT and you are encouraged to talk individually to PVIC faculty/students!

Prof Collins: [robert.collins@utoledo.edu](mailto:robert.collins@utoledo.edu); Prof. Ellingson: [randy.ellingson@utoledo.edu](mailto:randy.ellingson@utoledo.edu);  
Prof. Heben: [michael.heben@utoledo.edu](mailto:michael.heben@utoledo.edu); Prof. Podraza: [nikolas.podraza@utoledo.edu](mailto:nikolas.podraza@utoledo.edu);  
Prof. Yan: [yanfa.yan@utoledo.edu](mailto:yanfa.yan@utoledo.edu).

University of Toledo